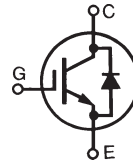


### GenX3™ 1400V IGBTs w/ Diode

**IXGH20N140C3H1**  
**IXGT20N140C3H1**

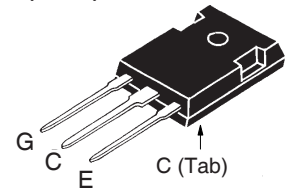
### High-Speed PT IGBTs for 20 - 50 kHz Switching



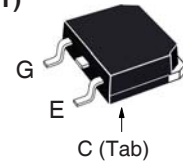
$$\begin{aligned} V_{CES} &= 1400V \\ I_{C100} &= 20A \\ V_{CE(sat)} &\leq 5.0V \\ t_{fi(typ)} &= 32ns \end{aligned}$$

| Symbol                        | Test Conditions                                                                  | Maximum Ratings                        |            |
|-------------------------------|----------------------------------------------------------------------------------|----------------------------------------|------------|
| $V_{CES}$                     | $T_J = 25^\circ C$ to $150^\circ C$                                              | 1400                                   | V          |
| $V_{CGR}$                     | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GE} = 1M\Omega$                        | 1400                                   | V          |
| $V_{GES}$                     | Continuous                                                                       | $\pm 20$                               | V          |
| $V_{GEM}$                     | Transient                                                                        | $\pm 30$                               | V          |
| $I_{C25}$                     | $T_C = 25^\circ C$                                                               | 42                                     | A          |
| $I_{C100}$                    | $T_C = 100^\circ C$                                                              | 20                                     | A          |
| $I_{CM}$                      | $T_C = 25^\circ C$ , 1ms                                                         | 108                                    | A          |
| $I_A$                         | $T_C = 25^\circ C$                                                               | 20                                     | A          |
| $E_{AS}$                      | $T_C = 25^\circ C$                                                               | 400                                    | mJ         |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_J = 125^\circ C$ , $R_G = 5\Omega$<br>Clamped Inductive Load | $I_{CM} = 40$<br>$V_{CE} \leq V_{CES}$ | A          |
| $P_C$                         | $T_C = 25^\circ C$                                                               | 250                                    | W          |
| $T_J$                         |                                                                                  | -55 ... +150                           | $^\circ C$ |
| $T_{JM}$                      |                                                                                  | 150                                    | $^\circ C$ |
| $T_{stg}$                     |                                                                                  | -55 ... +150                           | $^\circ C$ |
| $T_L$                         | 1.6mm (0.062 in.) from Case for 10s                                              | 300                                    | $^\circ C$ |
| $T_{SOLD}$                    | Plastic Body for 10 seconds                                                      | 260                                    | $^\circ C$ |
| $M_d$                         | Mounting Torque (TO-247)                                                         | 1.13/10                                | Nm/lb.in.  |
| <b>Weight</b>                 | TO-247                                                                           | 6                                      | g          |
|                               | TO-268                                                                           | 4                                      | g          |

TO-247 (IXGH)



TO-268 (IXGT)



G = Gate      C = Collector  
E = Emitter    Tab = Collector

### Features

- Optimized for Low Switching Losses
- Square RBSOA
- High Avalanche Capability
- Anti-Parallel Ultra Fast Diode
- International Standard Packages

### Advantages

- High Power Density
- Low Gate Drive Requirement

### Applications

- High Frequency Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |                       |
|---------------|-----------------------------------------------------------------------|-----------------------|------|-----------------------|
|               |                                                                       | Min.                  | Typ. | Max.                  |
| $V_{GE(th)}$  | $I_C = 250\mu A$ , $V_{CE} = V_{GE}$                                  | 3.0                   |      | 5.0 V                 |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 125^\circ C$ , Note 1    |                       |      | 100 $\mu A$<br>2.0 mA |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                    |                       |      | $\pm 100$ nA          |
| $V_{CE(sat)}$ | $I_C = I_{C100}$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 125^\circ C$     | 4.0<br>3.5            | 5.0  | V<br>V                |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                                                                 | Characteristic Values |      |                        |
|--------------|---------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|------------------------|
|              |                                                                                                                                             | Min.                  | Typ. | Max.                   |
| $g_{fs}$     | $I_C = I_{C100}, V_{CE} = 10\text{V}$ , Note 1                                                                                              | 10                    | 17   | S                      |
| $C_{ies}$    | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$                                                                                  |                       | 1790 | pF                     |
| $C_{oes}$    |                                                                                                                                             |                       | 145  | pF                     |
| $C_{res}$    |                                                                                                                                             |                       | 50   | pF                     |
| $Q_g$        | $I_C = I_{C100}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$                                                                           |                       | 88   | nC                     |
| $Q_{ge}$     |                                                                                                                                             |                       | 18   | nC                     |
| $Q_{gc}$     |                                                                                                                                             |                       | 30   | nC                     |
| $t_{d(on)}$  | Inductive load, $T_J = 25^\circ\text{C}$<br>$I_C = I_{C100}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 5\Omega$<br>Note 2  |                       | 19   | ns                     |
| $t_{ri}$     |                                                                                                                                             |                       | 12   | ns                     |
| $E_{on}$     |                                                                                                                                             |                       | 1.35 | mJ                     |
| $t_{d(off)}$ |                                                                                                                                             |                       | 110  | ns                     |
| $t_{fi}$     |                                                                                                                                             |                       | 32   | ns                     |
| $E_{off}$    |                                                                                                                                             |                       | 0.44 | mJ                     |
| $t_{d(on)}$  | Inductive load, $T_J = 125^\circ\text{C}$<br>$I_C = I_{C100}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 5\Omega$<br>Note 2 |                       | 22   | ns                     |
| $t_{ri}$     |                                                                                                                                             |                       | 13   | ns                     |
| $E_{on}$     |                                                                                                                                             |                       | 2.33 | mJ                     |
| $t_{d(off)}$ |                                                                                                                                             |                       | 144  | ns                     |
| $t_{fi}$     |                                                                                                                                             |                       | 380  | ns                     |
| $E_{off}$    |                                                                                                                                             |                       | 1.64 | mJ                     |
| $R_{thJC}$   | TO-247                                                                                                                                      |                       | 0.21 | $0.50^\circ\text{C/W}$ |
| $R_{thCK}$   |                                                                                                                                             |                       |      | $^\circ\text{C/W}$     |

## Reverse Diode (FRED)

| Symbol     | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                         | Characteristic Values |      |                       |
|------------|-----------------------------------------------------------------------------------------------------|-----------------------|------|-----------------------|
|            |                                                                                                     | Min.                  | Typ. | Max.                  |
| $V_F$      | $I_F = 20\text{A}, V_{GE} = 0\text{V}$ , Note 1<br>$T_J = 125^\circ\text{C}$                        |                       | 2.8  | 3.0 V                 |
| $I_{RM}$   | $I_F = 20\text{A}, V_{GE} = 0\text{V}$ ,<br>$-di_F/dt = 750\text{A}/\mu\text{s}, V_R = 800\text{V}$ |                       | 19   | A                     |
| $t_{rr}$   |                                                                                                     |                       | 70   | ns                    |
| $R_{thJC}$ |                                                                                                     |                       |      | $0.9^\circ\text{C/W}$ |

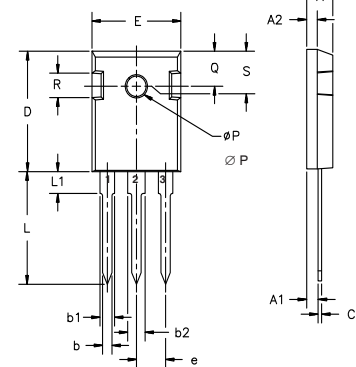
## Notes:

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}(\text{Clamp})$ ,  $T_J$  or  $R_G$ .

## ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

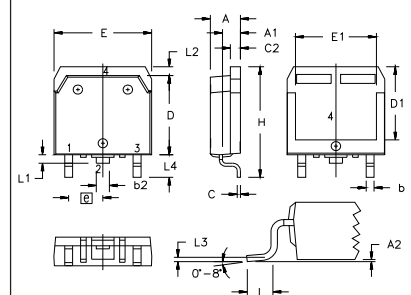
## TO-247 Outline



Terminals: 1 - Gate  
3 - Emitter  
2 - Collector

| Dim.           | Millimeter |       | Inches |       |
|----------------|------------|-------|--------|-------|
|                | Min.       | Max.  | Min.   | Max.  |
| A              | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub> | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub> | 2.2        | 2.6   | .059   | .098  |
| b              | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub> | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub> | 2.87       | 3.12  | .113   | .123  |
| C              | .4         | .8    | .016   | .031  |
| D              | 20.80      | 21.46 | .819   | .845  |
| E              | 15.75      | 16.26 | .610   | .640  |
| e              | 5.20       | 5.72  | 0.205  | 0.225 |
| L              | 19.81      | 20.32 | .780   | .800  |
| L <sub>1</sub> |            | 4.50  |        | .177  |
| ØP             | 3.55       | 3.65  | .140   | .144  |
| Q              | 5.89       | 6.40  | 0.232  | 0.252 |
| R              | 4.32       | 5.49  | .170   | .216  |
| S              | 6.15       | BSC   | .242   | BSC   |

## TO-268 Outline



Terminals: 1 - Gate  
3 - Emitter  
2 & 4 - Collector

| SYM            | INCHES |      | MILLIMETERS |       |
|----------------|--------|------|-------------|-------|
|                | MIN    | MAX  | MIN         | MAX   |
| A              | .193   | .201 | 4.90        | 5.10  |
| A <sub>1</sub> | .106   | .114 | 2.70        | 2.90  |
| A <sub>2</sub> | .001   | .010 | 0.02        | 0.25  |
| b              | .045   | .057 | 1.15        | 1.45  |
| b <sub>2</sub> | .075   | .083 | 1.90        | 2.10  |
| C              | .016   | .026 | 0.40        | 0.65  |
| C <sub>2</sub> | .057   | .063 | 1.45        | 1.60  |
| D              | .543   | .551 | 13.80       | 14.00 |
| D <sub>1</sub> | .488   | .500 | 12.40       | 12.70 |
| E              | .624   | .632 | 15.85       | 16.05 |
| E <sub>1</sub> | .524   | .535 | 13.30       | 13.60 |
| e              | .215   | BSC  | 5.45        | BSC   |
| H              | .736   | .752 | 18.70       | 19.10 |
| L              | .094   | .106 | 2.40        | 2.70  |
| L <sub>1</sub> | .047   | .055 | 1.20        | 1.40  |
| L <sub>2</sub> | .039   | .045 | 1.00        | 1.15  |
| L <sub>3</sub> | .010   | BSC  | 0.25        | BSC   |
| L <sub>4</sub> | .150   | .161 | 3.80        | 4.10  |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|                                                                                  |           |           |           |           |              |              |              |              |              |             |
|----------------------------------------------------------------------------------|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|                                                                                  | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|                                                                                  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |



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